M odi cation of the valence band electronic structure under A g intercalation underneath graphite m onolayer on N i(111)

Yu.S.Dedkov, M.Poygin, D.Vyalikh,

A. Starodubov, A.M. Shikin, and V.K. Adam chuk

Institute of Physics, St. Petersburg State University,

198904 St. Petersburg, Russia

Abstract

Angle-resolved photoem ission spectroscopy and Auger electron spectroscopy have been applied to study the intercalation process of silver underneath a m onolayer of graphite (M G) on N i(111). The room -tem perature deposition of silver on top of M G /N i(111) system leads to the islands-like grow th of A g on top of the M G. Annealing of the "as-deposited" system at tem perature of 350-450 C results in the intercalation of about 1-2M L of A g underneath M G on N i(111) independently of the thickness of pre-deposited A g lm (3-100A). The intercalation of A g is followed by a shift of the graphite-derived valence band states tow ands energies which are slightly larger than ones characteristic for pristine graphite. This observation is understood in terms of a weakening of chem ical bonding between the M G and the substrate in the M G /A g/N i(111) system with a sm all M G /N i(111) covalent contribution to this interaction. Corresponding author:

Yu.S.Dedkov

II.Physikalisches Institut

52056 Aachen, Germany

Tel: + + 49-241-8027091

Fax: + + 49-241-8022306

E-m ail: dedkov@physik.rwth-aachen.de

The continuing interest in carbon-based material has resulted in a number of studies of their magnetic, electronic, and transport properties which are interesting from technological as well as fundamental point of view [1,2]. The ability to alter the properties of graphite and graphite intercalation compounds (G IC s) makes them interesting candidates for a range of applications including, for example, magnetic storage, hard coating, and optical devices. A lso, quasi-two-dimensional or even one-dimensional character of mentioned structures gives the opportunity to use them as model systems for dimensional character of mentioned structures gives and chemistry.

In the last decades the system s on the basis of noble m etals (Cu, Au, Ag) intercalated underneath a m onolayer of graphite (MG) on top of Ni(111) were extensively investigated by m eans of high-resolution-electron-energy-loss-spectroscopy (HREELS) [3[6] and photoem ission spectroscopy (PES) [6,7] m ethods. These system s have attracted a strong interest due to a quasi two-dim ensional geom etric and electronic structure. In these noble m etal intercalation-like system s an unusual e ect of energetic shift of graphite-derived branches in the valence band electronic structure and the phonon vibration spectra after intercalation of noble m etals were observed. This e ect is caused by the weakening of the "MG-substrate" intercalation due to the noble m etal intercalation. From the other side, this intercalation-like system on the basis of MG and noble m etal can be chosen as a possible way of form ation of a at layered structure, in spite of the case of noble m etal deposition on pure N i(111) surface, where the form ation of three-dim ensional island-like structures was observed. In particular, in work [3] the form ation of at pseudom orphic copper layer on top of N i(111) was possible by using a benzene as surfacant with subsequent removing of benzene from the surface after intercalation process.

In this paper the investigations of the valence band electronic structure modi cation upon Ag intercalation underneath MG located on top of the Ni(111) by angle-resolved photoem ission spectroscopy (ARPES) are presented. This work is a continuation of HREELSinvestigations of this system [5]. In spite of our previous PES investigations of the analogous system s on the basis of copper and gold as intercalant [6,7], in the current work, the attention was attracted to the changes in the graphite-derived electronic structure as well as to estimation of am ount of intercalated Ag as a dependence of the annealing temperature as well as of the am ount of deposited Ag on top of MG/Ni(111) system.

The present investigations show that the most appropriate tem perature for intercalation of A g atom s underneath M G on N i(111) is in the range between 350 and 400-450 C. Above these tem peratures the partial system degradation was observed. As a result of A g atom s intercalation at 350-450 C the energetic shift of the graphite-derived valence band states was observed. In this case these branches are located at low er binding energies in com parison with the M G /N i(111) system that can be explained by the weakening of the "M G -substrate" interaction affer A g intercalation underneath M G.

As it was mentioned above one of the present work tasks was determ ination of the intercalated amount of Ag underneath MG on top of Ni(111). In the recent works [9,10] the process of Ag atom s intercalation underneath MG on Ir(111) textured foil was investigated. A uger electron spectroscopy (AES) and therm o-desorption spectroscopy (TDS) investigations showed that maxim alam ount of Ag which can be intercalated underneath MG is one monolayer (ML) in contrast to the Ag concentration deposited on top of MG. Earlier in our previous work [5] the assumption about intercalation of only 1M L of Ag underneath MG and that the rest of deposited Ag form ed a large 3D islands on top of MG /N i(111) system was made.

To make this problem clear in the present work the AES experiments for three dierent amount of pre-deposited Ag (3, 10 and 100A) were performed. For estimation of Ag intercalated amount the mean free path of AES electrons should be taken into account. In this case for careful analysis of the intercalation process the high kinetic energy (E_{kin}) AES lines of elements were chosen. As a result of AES investigations the amount of Ag intercalated underneath MG was estimated to about 2ML independently on thickness of pre-deposited amount of Ag (3-100A). This value is very small in comparison to the amount of Ag deposited on the sample surface before the intercalation. In this case the formation of large 3D islands of non-intercalated Ag is expected.

II. EXPERIMENTAL DETAILS

The experiments were carried out in two separated UHV experimental chambers equipped with low energy electron diraction (LEED) and AES optics, an ion gun and a gas in let system. Angle-resolved photoem ission measurements were carried out with ADES-type spectrometer at the Berliner Electronenspeciderring fur Synchrotronstrahlung (BESSY I, Berlin, Germany) using a monochromatic light with the photon energy of 50 eV from TGM 2 beam – line. Total energy resolution was 100 m eV and angle resolution was 1. The AES experiments were carried out by four-grid electron spectrometer with relative energy resolution of 0.25%. All spectra were collected in dN =dE mode with energy of primary electron beam of 1000 eV and m odulation voltage of 2V. The base pressure in the experim ental cham bers was better than 1 $\,10^{10}$ m bar.

M G was form ed on top of the N i(111) surface by cracking of propylene (C $_{3}$ H $_{6}$) at surface tem perature of 500 C using the recipe described in details in β {7]. Sam ple exposition at a propylene pressure of 1 10 ⁶ m bar during 4 m in was enough to form a well ordered M G layer on top of N i(111) surface. The crystallographic structure was checked by LEED and ordered hexagonal LEED picture with three-fold sym metry was observed β {7]. Ag lm s were deposited at room tem perature from melted Ag piece (purity 99.9%) supported by W w ire which was heated by current and thickness of the deposited layer was simultaneously m easured by water-cooled quartz m icrobalance monitor. The processes of Ag intercalation underneath M G on top of N i(111) surface was investigated at a substrate tem perature in the range between 350 and 500 C . Sam e sam ple preparation procedure of the intercalationlike system on the basis of Ag and M G was described earlier in our work [5] for HREELS investigations of the phonon structure of M G /Ag/N i(111) system.

III.EXPERIMENTAL RESULTS AND DISCUSSION

In Fig.1 a series of the norm alem ission valence band photoem ission spectra is presented for "as-deposited" 100A-thick Ag-overlayer on top of the MG/Ni(111) system as well as after annealing of the (Ag + MG/Ni(111)) system at di erent temperatures in the range between 350 and 500 C. These temperature regimes are appropriated for Ag-intercalation in accordance with our previous HREELS investigations [5]. For comparison, the corresponding spectrum for the initial MG/Ni(111) system is shown by open symbols. PES spectrum for the MG/Ni(111) system is characterized by pronounced $_{1v}$ and $_{2\beta v}$ graphite-derived features located at the binding energies (BE) of about 10.2 and 5 eV, respectively, and two N i3d-derived features with m axim a at 0.5 and 1.4 eV BE. Room -tem perature deposition of 100 A Ag leads to suppression of MG - and N i-derived states in the PES spectra. The dom inant features in the spectra are Ag 4d-derived states located in the BE range between 4 and 7 eV. D expite a signi cant am ount of deposited Ag (about of 100 A) the weaked N i 3d states at the BE of 0.5 and 1.5 eV and very weak $_{1v}$ graphite-derived features at about of 10 eV can be distinguished in the spectra that can testify an island-like character of "as-deposited" A g-layer. Additional feature observed at the Ferm i-level (E_F) can be related to the surface states characterized for m etallic silver [12].

A nnealing of the 100 A g/M G / N i(111) system at 350 C is followed by the restoring of the $_{1v}$ graphite-derived states and disappearing of the N i 3d states in the energy region between E_F and 1.5 eV BE. In comparison with the initial M G / N i(111) system the $_{1v}$ graphite-derived states are shifted towards lower BE by of 1.3 eV up to of about 9 eV BE. The A g 4d-derived features remain dominant ones in the PES spectra. Increase of annealing temperature up to 400 and 450 C leads to further decreasing of the BE of $_{1v}$ -derived states. A fiter annealing at 450 C the BE of the $_{1v}$ graphite-derived states reaches the value of about 8.3 eV relative to E_F . Further increase of annealing temperature up to 500 C is followed by reverse increasing of the BE of the $_{1v}$ -derived states. The structure of the A g 4d-derived states does not changed at these annealing temperatures. The restoring of the intensity of $_{1v}$ graphite-derived states and the decreasing of their BE after annealing of the A g/M G / N i(111) system at temperatures above than 350 C can be explained by the intercalation of A g atom s underneath M G on top of N i(111) and the change of the "M G -substrate" interaction after intercalation.

In F ig 2 the changes of the relative intensities of the $_{1v}$ graphite-derived states at 10.2 eV BE and the A g 4d-derived feature located at 4.5 eV BE are presented for the annealed system at di erent temperatures in comparison with those for the M G /N i(111) system and for the "as-deposited" A g overlayer on top of M G /N i(111) system. It can be seen that annealing at 350 C leads to a grow th of the intensity of the $_{1v}$ graphite-derived feature and suppression of the intensity of the A g 4d-derived one. Increase of the annealing temperature up to 400 and 450 C leads to the further increasing of the intensity of the $_{1v}$ graphite-derived states and suppression of the A g 4d-derived states. However, annealing at temperature of 500 C is followed by the decreasing of intensity of the $_{1v}$ graphite-derived states as well as by the increasing of the A g 4d-derived ones.

On the basis of the presented data (changes of the BEs and of the intensity of the graphite- and A g 4d-derived states) the optim altem perature for the A g-intercalation in the range between 350 and 450 C was found. At higher annealing tem perature leads to the start of the M G /A g/N i(111) system degradation process was observed.

In order to estim ate the quantity of intercalated A g underneath M G on top of the N i(111) surface the AES experiments were carried out. Three dierent thicknesses of A g were used (3, 10 and 100 A). The AES intensities of the C (K V V), A g (M $_5$ N $_{45}$ N $_{45}$), N i(L $_3$ M $_{45}$ M $_{45}$) and N i (M V V) lines with E_{kin} = 272, 351, 848, and 60 eV respectively, depending on annealing temperature for the case of 100 A of pre-deposited A g on top of M G /N i(111) system are shown in Fig.3a. The choice of these lines for quantitative analysis was caused by the possibility to carefully separate the contributions from dierent elements (C, A g and N i) and by the reason that the electrons with such kinetic energy have a larger m ean free path than

electrons with E_{kin} around 50 eV analyzed in PES experiments. Encircled numbers I and II in Fig.3a correspond to MG/Ni(111) system and system after deposition of corresponding amount of Ag on top of MG, respectively. A fter Ag deposition the intensities of the C and Ni AES peaks decreased and Ag AES peak increased. A fter annealing of the Ag/MG/Ni(111) system the situation is changed: intensity of the Ag AES peak is decreased and intensities of the carbon and N i peaks are increased. At annealing temperature of about 300 C the intensity of carbon peak is the sam e as for the MG/Ni(111) system. In this case the situation is following: the graphite layer is on the top of the system and Ag intercalation underneath MG on top of Ni(111) takes place. In the sam e time the NiAES peak has a visible intensity at least three times an aller in comparison with the MG/Ni(111) system.

For comparison, the changes of the intensity ratio of the N i and A g AES peaks with tem perature change are presented in F ig 3b and m arked by solid squares, circles and triangles for 3, 10 and 100 A of pre-deposited A g, respectively. For system s with 3 and 10 A of pre-deposited A g on top of the M G /N i(111) the behaviours of the AES spectra with changes of annealing tem perature are the sam e (not shown here): decreasing of the intensity of the carbon and N i AES peaks after deposition of A g and increasing ones after annealing at tem peratures above 250 C. For all three cases the intensity of the carbon AES peak for the system , which is produced by the annealing of the A g/M G /N i(111) system at 350–370 C, is nearly the sam e and has an intensity com parable with intensity of carbon AES peak for the M G /N i(111) system . In all cases the N i AES peaks were also observed. From the analysis of the F ig 3a and 3b them ain features can be pointed: (i) intensity of the N i AES peak for the case of 100 A pre-deposited A g after annealing procedure is two tim es sm aller than for the case of 3A pre-deposited A g, where intercalation of 1M L of Ag was supposed, (ii) for the

9

system with 100A of pre-deposited Ag the intensity of the NiAES peak after annealing is decreased by three times in comparison with MG/Ni(111) system, (iii) for all three systems the NiAES peak with kinetic energy of 60 eV is clearly visible (this peak has a sm all inelastic mean free path in comparison with other AES peaks). On the basis of this analysis one can conclude that for all three cases of pre-deposited Ag on top of MG/Ni(111) system, only about 2ML of Ag can be intercalated underneath MG on top of Ni(111) independently on thickness of pre-deposited Ag Im. This conclusion is in a good agreement with results of works [5,9,10] where the thickness of intercalated Ag was estimated as 1ML, but near some in perfections of the surface of the Ni crystal (as a defects, steps, dislocations etc.) the intercalations of two orm ore monolayers of Ag can be expected.

For analysis of the peaks intensities extracted from PES data the mean free path of photoelectrons at h = 50 eV has to be taken into account. From these estimations of the intensity changes of N i 3d states near E_F one can conclude that 2-3M Ls of covered layer on top of N i(111) (together with M G) should be enough to completely depress the intensity of these states near E_F . These estimations together with presented AES data lead to a conclusion that in case of Ag intercalation underneath M G only 1-2 m onolayers of Ag are intercalated underneath M G m atrix. The rest of Ag can decorate the defects at the surface and form a random ly-situated large 3D-islands as a bt of dislocations were observed by STM on M G surface as it was shown in previous investigations of copper intercalations underneath M G [7]. The next possibility is the agglom eration of Ag at the borders of the sam ple. This estimation can be compared with the results of work [6,7]. In case of Au the 1M L intercalation underneath M G on top of N i(111) the N i 3d states near E_F were also

fully depressed. In opposite, for C u intercalation the N i 3d states still can be distinguished. Such diferences in the N i 3d states behaviour for the noble m etal intercalation underneath M G on N i(111) can be explained by the nickel-copper alloy form ation and absence of such alloys for A u and A g at tem peratures essential for noble m etal intercalation.

In Fig.4 a series of angle-resolved PES spectra for the MG/Ag/Ni(111) system form ed by annealing of 100A Ag+M G /N i(111) system at 450 C are presented. Spectra were measured in K direction of the graphite surface B rillouin zone (SBZ). Corresponding dispersions of the main valence band graphite-derived electronic states are shown in Fig 5 for the system s form ed by annealing at tem peratures of 350, 400 and 450 C.A lso in Fig.5 the dispersion in -M direction for the MG/Ag/Ni(111) system with the 3A and 4.7A of the pre-deposited Ag is shown by open squares and circles, respectively. The measurements in this case were made with the He resonance lamp and photon energy was 40.8 eV. Here, for comparison the dispersion of the and graphite-derived states for the MG/Ni(111) system as well as for pristine graphite are shown by straight and dash-dotted lines, respectively. Sim ilar to Fig.1 the PES spectra presented in Fig.4 are characterized by dom inant contribution of the Ag 4d-derived features. The ne structure of the Ag 4d-derived states practically do not changed with the polar angle variation. These states are practically non-dispersive in the PES spectra. Besides the Ag 4d-derived structure the PES spectra are characterized by the 1v, 1v and 2;3v graphite-derived states with strong dispersion. Binding energy of the $_{1v}$ and $_{1v}$ states in the point of the SBZ (norm alem ission) are equal to 21.5 and $8.3 \, \text{eV}$, respectively. By increase of the polar angle the $_{1v}$ -states reach the position with the BEs lower than those for the Ag 4d-derived states. For polar angles over 25 ($k_{ii} > 1.4$ -1.5 A¹) the -states are splited in two features. One feature reaches the BE of about

3eV for k_{ii} 1.5A¹. Second feature has the lowest BE equals of about 1eV for the polar angles in the region of 30 ($k_{ij} = 1.7 \text{ A}^{-1}$) that corresponds to the \overline{K} point of graphite SBZ. By further increase of polar angle both states show decreasing intensities and shift towards higher BEs. Besides the 1v and 1v graphite-derived states, the 2:3v graphite-derived states can be distinguished in the PES spectra for polar angles over 20 (Fig.5). These states are also strongly dispersive. D ispersive dependencies for these states are presented in Fig.5. In com parison with the dispersion dependencies of the MG /Ni(111) system the branch of the 1y graphite-derived states is signi cantly shifted as whole towards lower BES by about of 1.5-2 eV after intercalation of A g atom s underneath M G on N i(111). In the \overline{K} point of the graphite SBZ the BE of the _{1v} states for the MG/Ag/Ni(111) system is about of 1eV in com parison with the BE about of 3 eV for the MG/Ni(111) system . Totally the $_{1v}$ states for the MG/Ag/Ni(111) system are located in the region between branches characteristic for pristine graphite and for the MG/Ni(111) system . In the region of the \overline{K} point they are located more close to the positions characteristic for pristine graphite. The $_{1v}$ states in the region of the point are located at the energy characteristic for pristine graphite. In the region of the \overline{K} point these states have the BE about of 16.5 eV. This energetic shift of the graphite-derived valence band states for the MG/Ni(111) system can be attributed to weakening of the interaction of MG with Ni-substrate after intercalation of Ag atoms. In accordance to [13,14] this interaction for the MG /Ni(111) system is caused by orbitalm ixing (hybridization) of the -states of MG with 3d-states of the substrate. Such hybridization is followed by electron redistribution from the bonding -states to antibonding -states that results in the weakening of the (C-C) bonds in the graphite layer and increase of the BE

of the graphite-derived states (di erent for the and states). Intercalation of A g atom s increases the distance between M G and N i-substrate and, as consequence, leads to decreasing of the M G - N i 3d interaction and to signi cantly lower BEs of the and graphite-derived states as compared to those in the M G /N i(111) system. The assumption about the weakening of the "M G -substrate" interaction after A g-intercalation is in agreement with the results of HREELS investigations of the M G /A g/N i(111) system [5] which displays the analogous elect of "still ening" of the graphite-derived phonon modes after A g-intercalation.

In some degree analogous energetic shift of the graphite-derived states were recently observed upon intercalation of gold and copper underneath M G on the N i(111) [6,7]. But in that case the and graphite-derived states were shifted upon Cu or Au intercalation up to the positions characteristic for pristine graphite. Such di erence between m odi cation of the PE spectra upon intercalation of Ag, Cu and Au can be explained by m ore com plex interaction of Ag with M G and N i-substrate. A coording to results of O shim a et al. calculations of the phonon m odes in the M G /Cu/N i and M G /A g/N i system s the interaction of M G with substrate after intercalation of Ag is m ore stronger than that, which realizes in the case of pristine graphite and the M g/Cu/N i(111) system [15].

On the basis of these experimental observations the following model can be proposed: after intercalation of Ag in the MG/Ni(111) system the covalent-like nature of interaction between MG and substrate is saving due to the (Ni-Ag) interaction. However, the strength of this interaction is lower than in the case of the MG/Ni(111) system. This assumption is supported by the experimental fact, which shows that the occupation of the

graphite-derived states and the appearance corresponding features in the PES spectra were not observed. This situation is opposite to the case of the alkalim etal intercalation underneath MG where these e ects were observed [13].

O ther interesting e ect observed after the Aq-intercalation is the splitting of the graphite-derived states in the PES spectra for polar angles over 25 (k_{ii} > 1.4 A 1). In our opinion the observed di erence in the energetic positions and the angle dependencies of both grahite-derived branches maxim a can be related to di erent behavior of the states in the regions of the \overline{K} and \overline{M} -point of the graphite SBZ.On this basis one can assume that the second branch of the states with maximum of the BE at 4 eV at k_{ii} 1.4 A 1 is similar to the behavior of the states in the region of the \overline{M} -point of the SBZ, i.e. it can be the "footprint" of the M direction (see, for comparison, the real dispersion in M direction shown by open symbols). It can be caused by som e dom ains disorientation in graphite monolayer which can arrive after Ag atom s intercalation. The BE value of the 1v-states observed in the region of the \overline{K} -point of the SBZ can be also understood from analogous positions. This part of the 1v graphite-derived branch can be also related to "footprint" of the _{1v} states in the <u>M</u> direction. The LEED pattern of the system after Ag atom s intercalation displays graphite-like (1 1) hexagonal structure characteristic for the MG /Ni(111) system with some weak strips rotated on 15 with respect to hexagonal ones. Such LEED patterns suggest that the prepared system is term inated by graphite-like dom ains with som e orientation m is t with respect to the N i(111) substrate, as it has been already observed for the MG/Cu/Ni(111) system β_{4} and has been described for the MG/Ag/Ni(111) system β_{5} . This disorientation is ordered one that leads to equivalent electronic structure both in the K and M directions of the monocrystalline graphite SBZ.From the other side the splitting of the graphite-derived states for the MG/Ni(111) system around \overline{K} -point of the graphite SBZ was theoretically predicted by Souzu et al. [16]. The energy dispersion of the

graphite-derived states along the high-symmetry line \overline{K} \overline{M} has a splitting-point at around of 2 eV BE. But for the isolated graphene layer which can be taken as an ideal case in the model of M G /A g/N i(111) intercalation-like system this splitting-point lies at E_F [16]. The possible energy shift can be caused by the rest interaction M G with substrate and deviation from the idealm odel of isolated graphene layer.

IV.CONCLUSION

On the basis of the PES and AES investigations of the Ag intercalation process underneath MG on top of the Ni(111) surface the following conclusions can be made: (i) optimal tem perature for intercalation of Ag underneath MG lies in the range 350-450 C; at tem perature above 500 C the degradation of the MG/Ag/Ni(111) system starts; (ii) the valence band electronic structure of the MG/Ag/Ni(111) system is characterized by the energetic shift of the and graphite-derived states as compared with the MG/Ni(111) system towards lower BEs by about of 1.5-2eV and 0.5-1eV, respectively; it is assumed that the observed changes of electronic structure is caused by the weakening of the -d interaction of the MG with substrate; the "orbitalm ixing" nature of this interaction is saving after Ag intercalation; (iii) on the basis of intensity changes analysis of C, Ag and NiAES peaks in intercalation process a conclusion about 1-2M L of intercalated Ag underneath MG on top of N i(111) was made and this value practically independent from the amount of A g deposited on top of the MG/Ni(111) system before intercalation; after intercalation of 1-2ML of Ag the form ation of the large A g islands which have a total square less than 50% of the surface can be expected; the agglom eration of the Ag at the surface dislocations and border of the

sam ple can not be excluded.

V.ACKNOW LEDGEMENTS

This work was performed in framework of INTASProject No.2001-2136 and Program of

M inistry of Industry and Science of Russian Federation "Fullerenes and Atom ic Clusters".

REFERENCES

- [1] M.S.D resselhaus and G.D resselhaus, Adv. Phys. 30, 139 (1981).
- [2] T. Mori, T. Tanaka, S. A. Gorovikov, S. L. Molodtsov, J. Phys. Soc. Japan 69, 3051 (2000).
- [3] A M. Shikin, D. Farias, and K. H. Rieder, Europhys. Lett. 44, 44 (1998).
- [4] A M. Shikin, D. Farias, K. H. Rieder, and V. K. Adam chuk, Surf. Sci. 427, 155 (1999).
- [5] D. Farias, K. H. Rieder, A. M. Shikin, and Yu. S. Dedkov, J. Phys.: Condens. M atter. 11, 8453 (1999).
- [6] A.M. Shikin, G.V. Prudnikova, V.K. Adam chuk, F.M oresco and K.H. Rieder, Phys. Rev. B 62, 13202 (2000).
- [7] Yu. S. Dedkov, A. M. Shikin, V. K. Adam chuk, S. L. Molodtsov, C. Laubschat, A. Bauer, and G. Kaindl, Phys. Rev. B 64, 035405 (2001).
- [8] H. Koschel, G. Held, P. Trischberger, W. Wildra, U. Birkenheuer and H.-P. Steinrck, Appl. Surf. Sci. 142, 18 (1999).
- [9] A. Ya. Tontegode, Prog. Surf. Sci. 38, 201 (1991).
- [10] A.Ya.Tontegode and E.V.Rut'kov, Usp.Phys.Nauk 163, 57 (1993) [Sov.Phys.Usp. 36, 1053 (1993)].
- [11] G. Le Lay, R. L. Johnson, R. Seem ann, F. Grey, R. Feidenhans'l, and M. Nielsen, Surf. Sci. 287–288, 539 (1993).

[12] S.D.Kevan and R.H.Gaylord, Phys.Rev.B 36, 5809 (1987).

- [13] A. Nagashima, N. Tejima, and C. Oshima, Phys. Rev. B 50, 17487 (1994).
- [14] C.Oshim a and A.Nagashim a, J.Phys.: Condens.Matter 9, 1 (1997).
- [15] D. Farias, K. H. Rieder, A. M. Shikin, V. K. Adam chuk, T. Tanaka and C. Oshima, Surf. Sci. 454–456, 437 (2000).
- [16] Y. Souzu and M. Tsukada, Surf. Sci. 326, 42 (1995).

Fig.1. PES spectra of the MG/Ni(111), 100A of Ag on MG/Ni(111), as well of Ag/MG/Ni(111) system after annealing at 350, 400, 450 and 500 C, respectively.

F ig 2. The changes of relative intensities of the $_{1v}$ graphite-derived state and the Ag 4d-derived feature after annealing of the Ag/M G/N i(111) system at di erent tem peratures in comparison with those for the M G/N i(111) system and for the "as-deposited" Ag overlayer on top of M G/N i(111) system.

Fig.3. a) Intensity of the C (KVV), Ag (M $_5N_{45}N_{45}$), N i(L₃M $_{45}M_{45}$) and N i(M VV) AES peaks in dependence from the annealing temperature for 100 A of pre-deposited Ag on top of M G /N i(111) system . b) temperature dependence of the intensity ratio (I(N i_{848})/I(A g_{351})) for di erent am ount of pre-deposited Ag on top of the M G /N i(111) system .

Fig.4. Series of the angle-resolved PES spectra measured at photon energy of 50 eV for the MG/Ag/Ni(111) system form ed after annealing of 100A Ag+MG/Ni(111) system at 450 C.

F ig 5 D ispersion plot of the m ain valence band graphite derived electronic states for the A g/M G /N i(111) system form ed after annealing of 100 A A g+ M G /N i(111) system at tem peratures of 350 (up triangles), 400 (down triangles) and 450 C (diam onds). The experim ental data points for the \overline{M} direction and photon energy 40.8 eV are shown by open symbols. Here, for comparison the dispersion of the and states for the M G /N i(111) system as well as for pristine graphite are shown by straight and dash-dotted lines, respectively.

19



Fig.1.



Fig.2.



Temperature (°C)

Fig.3.



Fig.4.



Fig.5.